WEST Search History

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DATE: Thursday, November 03, 2005

Hide?	Set Name	Query	Hit Count
		DB=USPT; PLUR=YES; OP=ADJ	
☐	L8	L7 and drain and source	29
☐	L7	L6 and transistor	29
☐	L6	L5 and substrate	29
☐	L5	L4 and floating gate	29
☐	L4	gate and (a-SiC or amorphous silicon carbide)	322
		DB=JPAB; PLUR=YES; OP=ADJ	
☐	L3	L2 and (a-SiC or amorphous silicon carbide)	0
☐	L2	floating and substrate	5518
		DB=USPT; PLUR=YES; OP=ADJ	
☐	L1	6835638 or 6936849	2

END OF SEARCH HISTORY